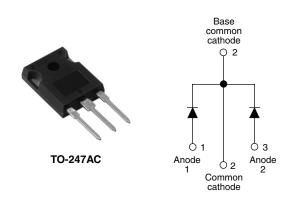
Vishay High Power Products

HEXFRED[®] Ultrafast Soft Recovery Diode, 2 x 8 A



600 V

1.7 V

2 x 8 A

18 ns

150 °C

65 nC

240 A/µs

PRODUCT SUMMARY

 V_{R}

V_F at 8 A at 25 °C

I_{F(AV)}

trr (typical)

T_J (maximum)

Qrr

dI(rec)M/dt

F	E	A	Т	U	R	E	S

- Ultrafast recovery
- Ultrasoft recovery
- Very low I_{RRM}
- Very low Q_{rr}
- Specified at operating conditions
- Lead (Pb)-free
- · Designed and qualified for industrial level

BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION

HFA16PA60C is a state of the art center tap ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 8 A per leg continuous current, the HFA16PA60C is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RBM}) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA16PA60C is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Cathode to anode voltage	VR		600	V		
Maximum continuous forward currentper leg		T _C = 100 °C	8			
per device			16	А		
Single pulse forward current	I _{FSM}		60	A		
Maximum repetitive forward current	I _{FRM}		24			
Maximum neuror discinction	Р	T _C = 25 °C	36	W		
Maximum power dissipation	PD	T _C = 100 °C	14	vv		
Operating junction and storage temperature range	T _J , T _{Stg}		- 55 to + 150	°C		

* Pb containing terminations are not RoHS compliant, exemptions may apply



COMPLIANT

HFA16PA60CPbF



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ELECTRICAL SPECIFICATIONS PER LEG ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA		600	-	-	
Maximum forward voltage	V _{FM}	I _F = 8.0 A	See fig. 1	-	1.4	1.7	V
		I _F = 16 A		-	1.7	2.1	
		I _F = 8.0 A, T _J = 125 °C		-	1.4	1.7	
Maximum reverse	I _{RM}	$V_{R} = V_{R}$ rated	See fig. 2	-	0.3	5.0	μA
leakage current		T_J = 125 °C, V_R = 0.8 x V_R rated		-	100	500	
Junction capacitance	CT	V _R = 200 V	See fig. 3	-	10	25	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body		-	8.0	-	nH

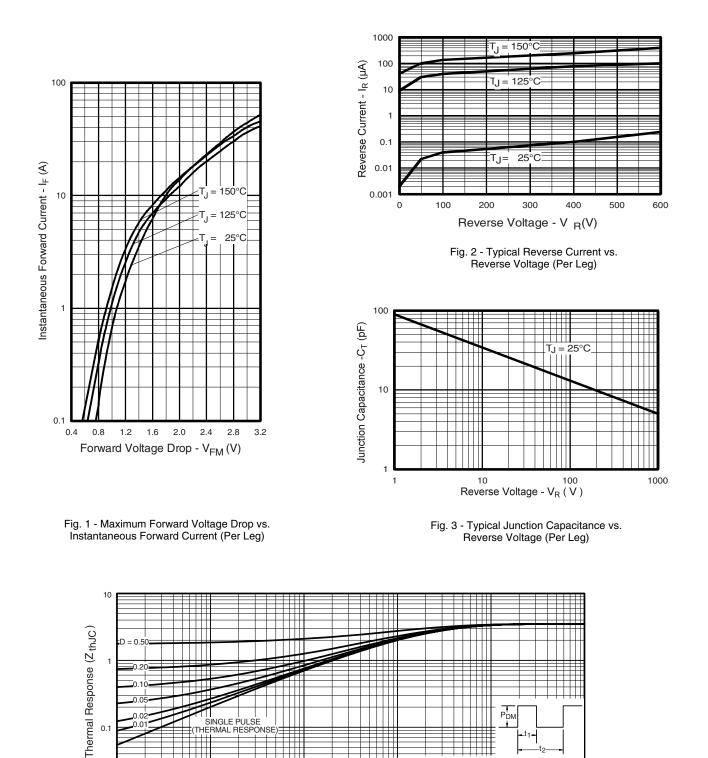
DYNAMIC RECOVERY CHARACTERISTICS PER LEG (T_J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
	t _{rr}	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200$	0 Α/μs, V _R = 30 V	-	18	-	ns
Reverse recovery time See fig. 5, 6 and 16	t _{rr1}	T _J = 25 °C	I _F = 8.0 A dI _F /dt = 200 A/μs V _R = 200 V	-	37	55	
	t _{rr2}	T _J = 125 °C		-	55	90	
Peak recovery current	I _{RRM1}	T _J = 25 °C		-	3.5	5.0	A nC
See fig. 7 and 8	I _{RRM2}	T _J = 125 °C		-	4.5	8.0	
Reverse recovery charge	Q _{rr1}	T _J = 25 °C		-	65	138	
See fig. 9 and 10	Q _{rr2}	T _J = 125 °C		-	124	360	
Peak rate of fall recovery	dl _{(rec)M} /dt1	T _J = 25 °C		-	240	-	A/µs
current during t _b See fig. 11 and 12	dI _{(rec)M} /dt2	T _J = 125 °C		-	210	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	L TEST CONDITIONS		TYP.	MAX.	UNITS	
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C	
Junction to case, single leg conducting			-	-	3.5		
Junction to case, both leg conducting	– R _{thJC}		-	-	1.75	K/W	
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	40	N/ V V	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.25	-		
Maight			-	6.0	-	g	
Weight			-	0.21	-	oz.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf ⋅ cm (lbf ⋅ in)	
Marking device		Case style TO-247AC (JEDEC)	HFA16PA60C		•		



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0.01

0.0001

t₁, Rectangular Pulse Duration (sec) Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

0.001

Notes

0.01

1. Duty factor D = t_1 / t_2 2. Peak T_J=P _{DM} x Z_{thJC}

+ T_C

0.1

HFA16PA60CPbF

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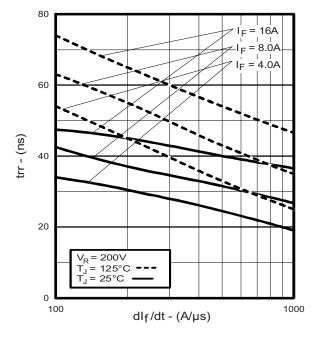
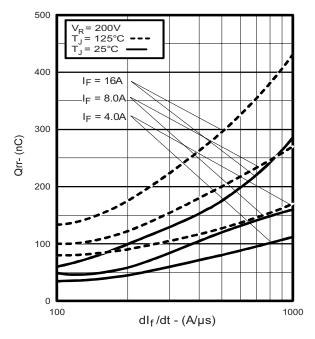
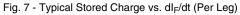


Fig. 5 - Typical Reverse Recovery Time vs. dI_F/dt (Per Leg)



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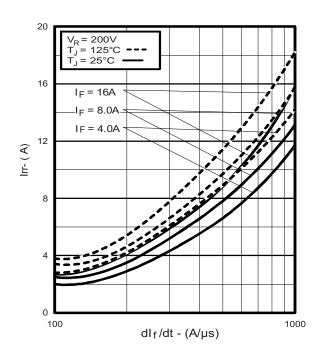


Fig. 6 - Typical Recovery Current vs. dl_F/dt (Per Leg)

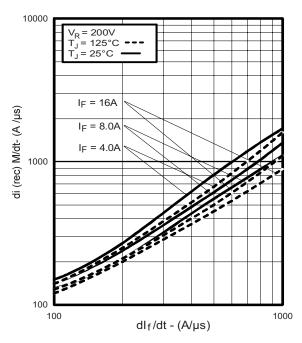


Fig. 8 - Typical $dI_{(rec)M}/dt$ vs. dI_F/dt (Per Leg)



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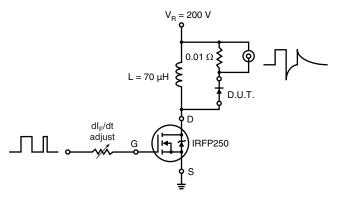


Fig. 9 - Reverse Recovery Parameter Test Circuit

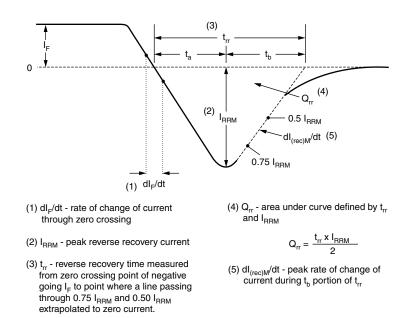


Fig. 10 - Reverse Recovery Waveform and Definitions

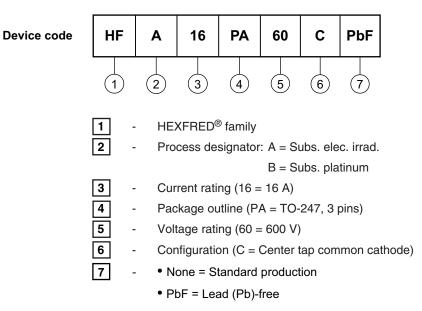
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ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95223				
Part marking information	http://www.vishay.com/doc?95226			



Vishay

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